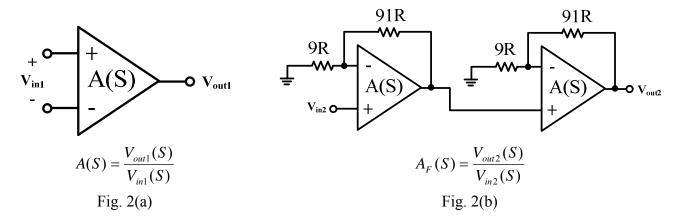
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- 1. (a) With less than 25 words to list the name of the four feedback amplifiers (e.g. Trans... amplifier) and their corresponding topologies (e.g. series-shunt). (12%)
- (b) Show how to derive A circuit and β circuit for a voltage amplifier. (8%)
- 2. A single-pole amplifier as shown in Fig.2(a) is designed to have a low-frequency gain of 100 and a pole at 10^6 Hz (i.e. $2\pi \times 10^6$ rad/sec). The single-pole amplifier (transfer function=A(S)) is used to design a feedback amplifier (transfer function=A_F(S) as shown in Fig.2(b).
- (a) Derive A(S)) and draw its Bode plot. (4%) (b) What's the feedback type of the internal stage of the feedback amplifier? β for the internal stage=? (8%) (c) Derive A_F(S) and draw its Bode plot. (4%) (d)If the gain of the single-pole amplifier is decreased by 20%, what is the corresponding gain decrease in the feedback amplifier? (4%)



- 3. With less than 20 words, please give definitions for the following items of an operation amplifier.
- (a) Slew Rate (7%)
- (b) Unity-Gain-Band-Width (6%)
- (c) Amplifier with rail-to-rail input operation (7%)
- 4. For a particular design of the two-stage CMOS op amp of Fig. 4. (Numerical answer is required.)
- (a) ± 1.65 -V supplies are utilized and all transistors except for M6 and M7 are operated with overdrive voltages of 0.35-V magnitude; M6 and M7 use overdrive voltages of 0.45-V magnitude. The fabrication process employed provides $V_{tn}=|V_{tp}|=0.5$ -V. Find the input common-mode range and the range allowed for v_o . (10%)
- (b) With the process parameter $V'_{An}=|V'_{Ap}|=20V/\mu m$. Find A_1 , A_2 , and A_2 if all devices are $1\mu m$ long, $V_{ov1}=0.2$ -V, and $V_{ov6}=0.5$ -V. Also, find the op-amp output resistance obtained when the second stage is biased at 0.45mA. (A_1 and A_2 represent the A of the first and the second stage, respectively) (10%)

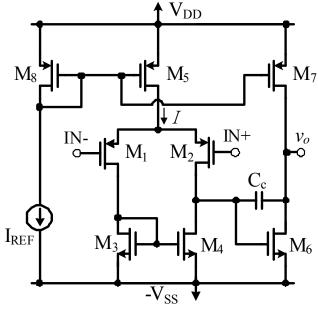


Fig. 4

5. As shown in Fig. 5, for the folded-cascode op amp utilizing power supplies of ± 1.65 -V, find the values of V_{BIAS1} , V_{BIAS2} , and V_{BIAS3} to maximize the allowable range V_{ICM} and v_o . Assume that all transistors are operated at equal overdrive voltages of 0.2-V. Assume $|V_t|$ for all devices is 0.5-V. Specify the maximum range of V_{ICM} and of v_o . (20%)

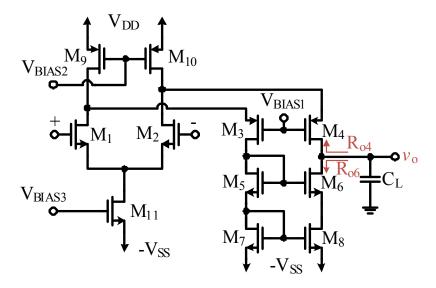


Fig. 5